NSN 5961-01-372-8122

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-372-8122 **Inclosure Material:** Plastic **Overall Length:** 0.375 inches **Overall Width:** 0.340 inches **Component Name And Quantity:** 3 semiconductor device diode and 2 transistor **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 30.0 gate to source voltage all transistor and 90.0 drain to source voltage all transistor and 90.0 drain to gate voltage all transistor **Current Rating Per Characteristic:** 900.00 milliamperes drain current all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 22 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: